

CR2AS-8UE

400V - 2A – Thyristor Low Power Use R07DS1229EJ0100 Rev.1.00 Oct 09, 2014

Features

 $\bullet \quad I_{T(AV)}: 2 A$

V_{DRM}: 400 V
 I_{GT}: 100 μA

• Non-Insulated Type

• Planar Type

Outline

RENESAS Package code: PRSS0004ZG-A

(Package name: MP-3A)



2, 4

1. Cathode

2. Anode

3. Gate

4. Anode

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
Repetitive peak reverse voltage	V_{RRM}	400	V
Non-repetitive peak reverse voltage	V_{RSM}	500	V
Repetitive peak off-state voltage Note1	V_{DRM}	400	V

Note: 1. With gate to cathode resistance $R_{\text{GK}}\text{=}1\text{k}\Omega$

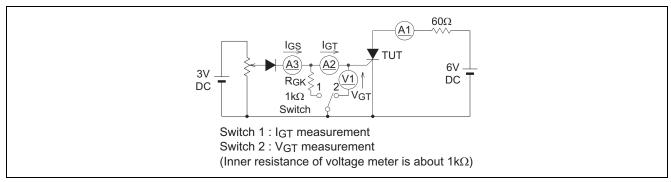
Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T(RMS)}	4	Α	
Average on-state current	I _{T(AV)}	2	A	Commercial frequency, sine half wave 180° conduction, Tc=101°C Note2
Surge on-state current	I _{TSM}	20	А	60Hz sine half wave, 1full cycle, peak value, non-repetitive
I ² t for fusing	l ² t	1.7	A ² s	Value corresponding to 1cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P _{GM}	0.5	W	
Average gate power dissipation	P _{G(AV)}	0.1	W	
Peak gate forward voltage	V_{FGM}	6	V	
Peak gate reverse voltage	V_{RGM}	6	V	
Peak gate forward current	I _{FGM}	0.2	Α	
Junction temperature	Tj	- 40 to +125	°C	
Storage temperature	Tstg	- 40 to +125	°C	
Mass	_	0.32	g	Typical value

Electrical Characteristics

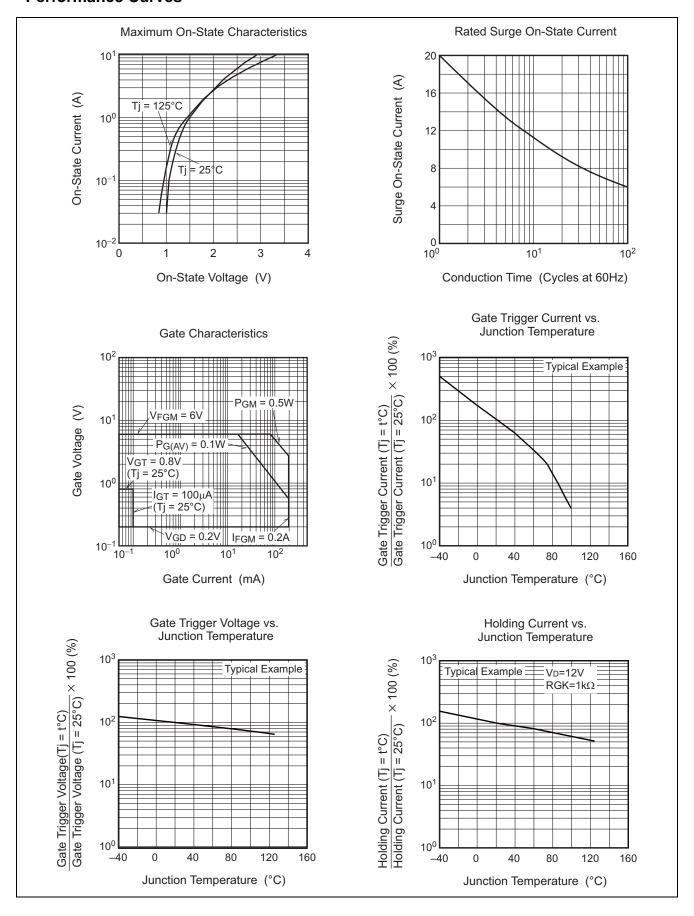
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak reverse current	I _{RRM}	_	_	0.1	mA	Tj = 125°C, V _{RRM} applied
						$R_{GK} = 1 k\Omega$
Repetitive peak off-state current	I _{DRM}	_	_	0.1	mA	Tj = 125°C, V _{DRM} applied
						$R_{GK} = 1 k\Omega$
On-state voltage	V_{TM}	_	_	2.2	V	Tj = 25°C, I _{TM} = 4 A
						instantaneous value
Gate trigger voltage	V_{GT}	_	_	8.0	V	$Tj = 25^{\circ}C, V_D = 6 V,$
						$I_T = 0.1 A^{\text{Note3}}$
Gate non-trigger voltage	V_{GD}	0.2	_	_	V	$Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$
						$R_{GK} = 1 k\Omega$
Gate trigger current	I _{GT}	1	_	100	μA	Tj = 25°C, V _D = 6 V,
						$I_T = 0.1 A^{\text{Note3}}$
Holding current	I _H	_	_	3	mA	Tj = 25°C, V _D = 12 V
						$R_{GK} = 1 k\Omega$
Thermal resistance	R _{th(j-c)}			4.4	°C/W	Junction to case Note2

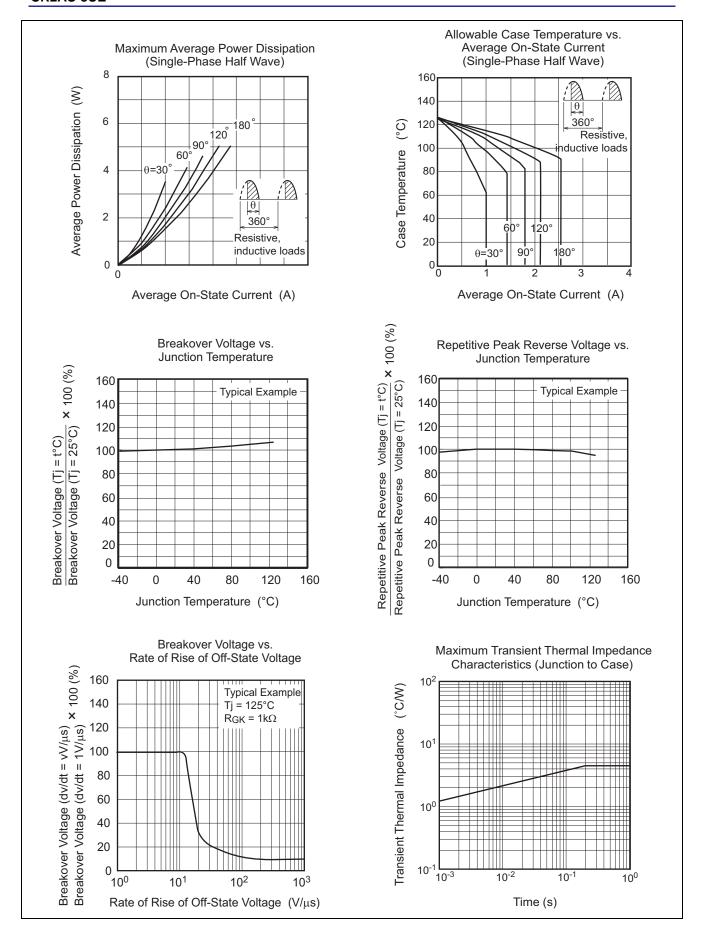
Note: 2. The measurement point for case temperature is at anode tab.

Note: 3. I_{GT} , V_{GT} measurement circuit

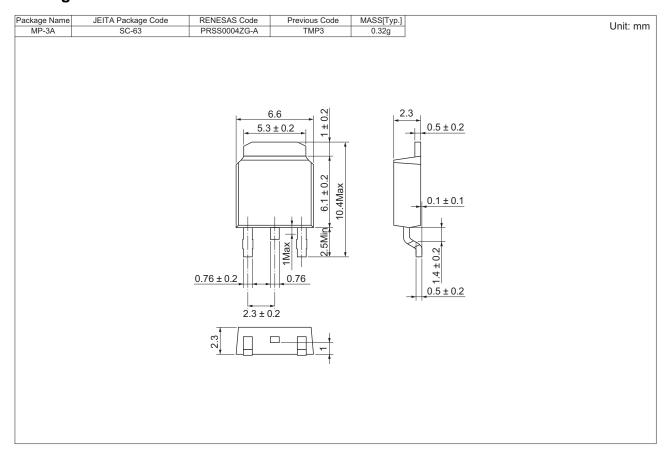


Performance Curves





Package dimensions



Ordering Information

Orderable Part Number	Packing	Quantity	Remark
CR2AS-8UE#B00	Tube	75 pcs.	
CR2AS-8UE-A2#B00	Tube	75 pcs.	A2 Lead forming
CR2AS-8UE-T13#B00	Embossed Tape	3000 pcs.	Taping direction "T1"

Note: Please confirm the specification about the shipping in detail.

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